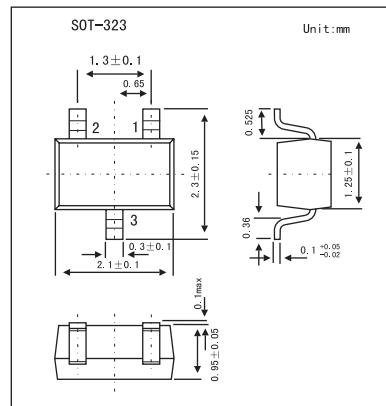


1PS70SB82;1PS70SB84 1PS70SB85;1PS70SB86

■ Features

- Low forward voltage
- Very small SMD plastic package
- Low diode capacitance.



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Min	Max	Unit
Continuous reverse voltage	V _R		15	V
Continuous forward current	I _F		30	mA
Storage temperature	T _{stg}	-65	+150	°C
Junction temperature	T _J		125	°C
Thermal resistance from junction to ambient	R _{th j-a}		625	K/W

■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Conditions	Typ	Max	Unit
Forward voltage	V _F	I _F = 1 mA		340	mV
		I _F = 30 mA		700	
Differential diode forward resistance	R _D	f = 1 MHz; I _F = 5 mA	12		Ω
Continuous reverse current	I _R	V _R = 1 V; note 1		0.2	μ A
Diode capacitance	C _d	V _R = 0 V; f = 1 MHz	1		pF

Note

1. Pulsed test: tp = 300 μ s; δ = 0.02.

■ Marking

Type	1PS70SB82	1PS70SB84	1PS70SB85	1PS70SB86
Marking	88	87	85	86